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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	ARM7®
Core Size	32-Bit Single-Core
Speed	60MHz
Connectivity	I²C, SPI, SSI, SSP, UART/USART, USB
Peripherals	DMA, PWM, WDT
Number of I/O	38
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 11x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	-
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/str751fr0t6

periodic interrupt. It is clocked by an external 32.768 kHz oscillator or the internal low power RC oscillator. The RC has a typical frequency of 300 kHz and can be calibrated.

WDG (watchdog timer)

The watchdog timer is based on a 16-bit downcounter and 8-bit prescaler. It can be used as watchdog to reset the device when a problem occurs, or as free running timer for application time out management.

Timebase timer (TB)

The timebase timer is based on a 16-bit auto-reload counter and not connected to the I/O pins. It can be used for software triggering, or to implement the scheduler of a real-time operating system.

Synchronizable standard timers (TIM2:0)

The three standard timers are based on a 16-bit auto-reload counter and feature up to 2 input captures and 2 output compares (for external triggering or time base / time out management). They can work together with the PWM timer via the Timer Link feature for synchronization or event chaining. In reset state, timer Alternate Function I/Os are connected to the same
I/O ports in both 64-pin and 100-pin devices. To optimize timer functions in 64-pin devices, timer Alternate Function I/Os can be connected, or “remapped”, to other I/O ports as summarized in *Table 3* and detailed in *Table 6*. This remapping is done by the application via a control register.

Table 3. Standard timer alternate function I/Os

Standard timer functions		Number of alternate function I/Os		
		100-pin package	64-pin package	
			Default mapping	Remapped
TIM 0	Input Capture	2	1	2
	Output Compare/PWM	2	1	2
TIM 1	Input Capture	2	1	1
	Output Compare/PWM	2	1	1
TIM 2	Input Capture	2	2	2
	Output Compare/PWM	2	1	2

Any of the standard timers can be used to generate PWM outputs. One timer (TIM0) is mapped to a DMA channel.

Motor control PWM timer (PWM)

The Motor Control PWM Timer (PWM) can be seen as a three-phase PWM multiplexed on 6 channels. The 16-bit PWM generator has full modulation capability (0...100%), edge or centre-aligned patterns and supports dead-time insertion. It has many features in common with the standard TIM timers which has the same architecture and it can work together with the TIM timers via the Timer Link feature for synchronization or event chaining.The PWM timer is mapped to a DMA channel.

Table 6. STR750F pin description (continued)

Pin n°				Pin name	Type	Input				Output			Usable in Standby	Main function (after reset)	Alternate function	
LQFP100(1)	LFBGA100(1)	LQFP64(2)	LFBGA64(2)			Input Level	floating	pu/pd	Ext. int /Wake-up	Capability	OD (3)	PP				
7	D1	5	D1	P0.29 / TIM1_TI1 / ADC_IN8	I/O	T_T	**X**	X		O2	X	X		**Port 0.29**	TIM1: Input Capture 1	ADC: Analog input 8
8	E1	6	D2	P0.28 / TIM1_OC1	I/O	T_T	**X**	X		O2	X	X		**Port 0.28**	TIM1: Output Compare 1	
9	E5	7	D3	TEST	I									Reserved, must be tied to ground		
10	E4	8	D4	VSS_IO	S									Ground Voltage for digital I/Os		
11	E2			P0.23 / UART1_RTS / ADC_IN6	I/O	T_T	**X**	X		O2	X	X		**Port 0.23**	UART1: Ready To Send output(4)	ADC analog input 6
12	F5			P2.04 / TIM2_OC1	I/O	T_T	**X**	X		O2	X	X		**Port 2.04**	TIM2: Output Compare 1(4)	
13	F1			P2.03 / UART1_RTS	I/O	T_T	**X**	X		O2	X	X		**Port 2.03**	UART1: Ready To Send output(4)	
14	F4			P2.02	I/O	T_T	**X**	X		O2	X	X		**Port 2.02**		
15	E3			P0.22 / UART1_CTS / ADC_IN5	I/O	T_T	**X**	X		O2	X	X		**Port 0.22**	UART1: Clear To Send input	ADC: Analog input 5
16	F2	9	E4	P0.21 / UART1_TX	I/O	T_T	**X**	X		O2	X	X		**Port 0.21**	UART1: Transmit data output (remappable to P0.15)(4)	
17	F3	10	E3	P0.20 / UART1_RX	I/O	T_T	**X**	X		O2	X	X		**Port 0.20**	UART1: Receive data input (remappable to P0.14)(4)	
18	G3	11	E2	P1.19 / JTMS	I/O	T_T	X	X		O2	X	X		**JTAG mode selection input(6)**	Port 1.19	
19	G2	12	E1	P1.18 / JTCK	I/O	T_T	X	X		O2	X	X		**JTAG clock input(6)**	Port 1.18	
20	H3	13	F4	P1.17 / JTDO	I/O	T_T	X	X		O8	X	X		**JTAG data output(6)**	Port 1.17	
21	H2	14	F3	P1.16 / JTDI	I/O	T_T	X	X		O2	X	X		**JTAG data input(6)**	Port 1.16	
22	G1	15	F2	NJTRST	I	T_T								JTAG reset input(5)		
23	G4			P2.01	I/O	T_T	**X**	X		O2	X	X		**Port 2.01**		
24	G5			P2.00	I/O	T_T	**X**	X		O2	X	X		**Port 2.00**		
25	H1	16	F1	P0.13 / RTCK / UART0_RTS UART2_TX	I/O	T_T	X	X		O8	X	X		**JTAG return clock output(6)**	Port 0.13 / UART0: Ready To Send output(4)	UART2: Transmit Data output (when remapped)(8)

Table 6. STR750F pin description (continued)

Pin n°				Pin name	Type	Input				Output			Usable in Standby	Main function (after reset)	Alternate function
LQFP100(1)	LFBGA100(1)	LQFP64(2)	LFBGA64(2)			Input Level	floating	pu/pd	Ext. int /Wake-up	Capability	OD (3)	PP			
43	H9			P2.16	I/O	T_T	X	X		O2	X	X		**Port 2.16**	
44	J9	27	G5	VDD_IO	S									Supply voltage for digital I/Os	
45	K9	28	G7	VDDA_PLL	S									Supply voltage for PLL	
46	K8	29	H7	XT2										4 MHz main oscillator	
47	K7	30	H8	XT1											
48	J10	31	G6	VSS_IO	S									Ground voltage for digital I/Os	
49	K10	32	G8	VSSA_PLL	S									Ground voltage for PLL	
50	J8			P2.15	I/O	T_T	X	X		O2	X	X		**Port 2.15**	
51	H8			P2.14	I/O	T_T	X	X		O2	X	X		**Port 2.14**	
52	G8	33	F5	V18REG	S									Stabilization for main voltage regulator. Requires external capacitors of at least 10µF between V18REG and VSS18. See *Figure 4.2*. To be connected to the 1.8V external power supply when embedded regulators are not used,	
53	F8	34	F6	VSS18	S									Ground Voltage for the main voltage regulator	
54	F9	35	F7	VSSBKP	S									Stabilization for low power voltage regulator.	
55	G9	36	E7	V18BKP	S									Ground Voltage for the low power voltage regulator. Requires external capacitors of at least 1µF between V18BKP and VSSBKP. See *Figure 4.2*. To be connected to the 1.8V external power supply when embedded regulators are not used,	
56	H10	37	F8	XRTC1									X	32 kHz oscillator for Realtime Clock	
57	G10	38	E8	XRTC2									X		
58	E7	39	E5	NRSTOUT	O								X	Reset output	
59	E9	40	E6	NRSTIN	I	T_T							X	Reset input	
60	D6			P1.15 / WKP_STDBY	I	T_T	X		EIT15				X	**Port 1.15**	Wake-up from STANDBY input pin
61	B8			P2.13	I/O	T_T	X	X		O2	X	X		**Port 2.13**	
62	D9			P2.12	I/O	T_T	X	X		O2	X	X		**Port 2.12**	
63	F10	41 (7)	D8 (7)	P0.15 / CAN_TX	I/O	T_T	X	X		O2	X	X		**Port 0.15**	CAN: Transmit data output
64	E10	42 (7)	C8 (7)	P0.14 / CAN_RX	I/O	T_T	X	X	EIT5	O2	X	X		**Port 0.14**	CAN: Receive data input
65	D10	41 (7)	D8 (7)	USB_DN	I/O									USB: bidirectional data (data -)	
66	C10	42 (7)	C8 (7)	USB_DP	I/O									USB: bidirectional data (data +)	
67	B9	43	B8	P1.03 / TIM2_TI2	I/O	T_T	X	X		O2	X	X		**Port 1.03**	TIM2: Input Capture / trigger / external clock 2 (remappable to P0.07)(8)

Table 6. STR750F pin description (continued)

Pin n°				Pin name	Type	Input				Output			Usable in Standby	Main function (after reset)	Alternate function	
LQFP100(1)	LFBGA100(1)	LQFP64(2)	LFBGA64(2)			Input Level	floating	pu/pd	Ext. int /Wake-up	Capability	OD (3)	PP				
91	A4	59	A3	P1.04 / PWM3N / ADC_IN9	I/O	T_T	**X**	X		O4	X	X		**Port 1.04**	PWM: PWM3 complementary output(4)	ADC: analog input 9
92	A3			P1.14 / ADC_IN15	I/O	T_T	**X**	X		O8	X	X		**Port 1.14**	ADC: analog input 15	
93	A2			P1.13 / ADC_IN14	I/O	T_T	**X**	X	EIT13	O8	X	X		**Port 1.13**	ADC: analog input 14	
94	D5			P1.01 / TIM0_TI2	I/O	T_T	**X**	X		O2	X	X		**Port 1.01**	TIM0: Input Capture / trigger / external clock 2 (remappable to P0.05)(8)	
95	E6			P1.00 / TIM0_OC2	I/O	T_T	**X**	X		O2	X	X		**Port 1.00**	TIM0: Output compare 2 (remappable to P0.04)(8)	
96	C4	60	C4	V18	S									Stabilization for main voltage regulator. Requires external capacitors 33nF between V18 and VSS18. See *Figure 4.2*. To be connected to the 1.8V external power supply when embedded regulators are not used.		
97	D4	61	C5	VSS18	S									Ground Voltage for the main voltage regulator.		
98	D3	62	A2	VSS_IO	S									Ground Voltage for digital I/Os		
99	C3	63	B2	VDD_IO	S									Supply Voltage for digital I/Os		
100	A1	64	A1	P0.03 / TIM2_TI1 / ADC_IN1	I/O	T_T	**X**	X		O2	X	X		**Port 0.03**	TIM2: Input Capture / trigger / external clock 1	ADC: analog input 1

1. For STR755FVx part numbers, the USB pins must be left unconnected.
2. The non available pins on LQPFP64 and LFBGA64 packages are internally tied to low level.
3. None of the I/Os are True Open Drain: when configured as Open Drain, there is always a protection diode between the I/O pin and VDD_IO.
4. In the 100-pin package, this Alternate Function is duplicated on two ports. You can configure one port to use this AF, the other port is then free for general purpose I/O (GPIO), external interrupt/wake-up lines, or analog input (ADC_IN) where these functions are listed in the table.
5. It is mandatory that the NJTRST pin is reset to ground during the power-up phase. It is recommended to connect this pin to NRSTOUT pin (if available) or NRSTIN.
6. After reset, these pins are enabled as JTAG alternate function see (*Port reset state on page 16*). To use these ports as general purpose I/O (GPIO), the DBGOFF control bit in the GPIO_REMAP0R register must be set by software (in this case, debugging these I/Os via JTAG is not possible).
7. There are two different TQFP and BGA 64-pin packages: in the first one, pins 41 and 42 are mapped to USB DN/DP while for the second one, they are mapped to P0.15/CAN_TX and P0.14/CAN_RX.
8. For details on remapping these alternate functions, refer to the GPIO_REMAP0R register description.

6 Electrical parameters

6.1 Parameter conditions

Unless otherwise specified, all voltages are referred to V_{SS}.

6.1.1 Minimum and maximum values

Unless otherwise specified the minimum and maximum values are guaranteed in the worst conditions of ambient temperature, supply voltage and frequencies by tests in production on 100% of the devices with an ambient temperature at $T_A$max (given by the selected temperature range).

Data based on product characterisation, design simulation and/or technology characteristics are indicated in the table footnotes and are not tested in production. Based on characterization, the minimum and maximum values refer to sample tests and represent the mean value plus or minus three times the standard deviation (mean±3Σ).

6.1.2 Typical values

Unless otherwise specified, typical data are based on T_A=25° C, V_{DD_IO}=3.3 V (for the 3.0 V≤V_{DD_IO}≤3.6 V voltage range) and V_{18}=1.8 V. They are given only as design guidelines and are not tested.

Typical ADC accuracy values are determined by characterization of a batch of samples from a standard diffusion lot over the full temperature range, where 95% of the devices have an error less than or equal to the value indicated (mean±2Σ).

6.1.3 Typical curves

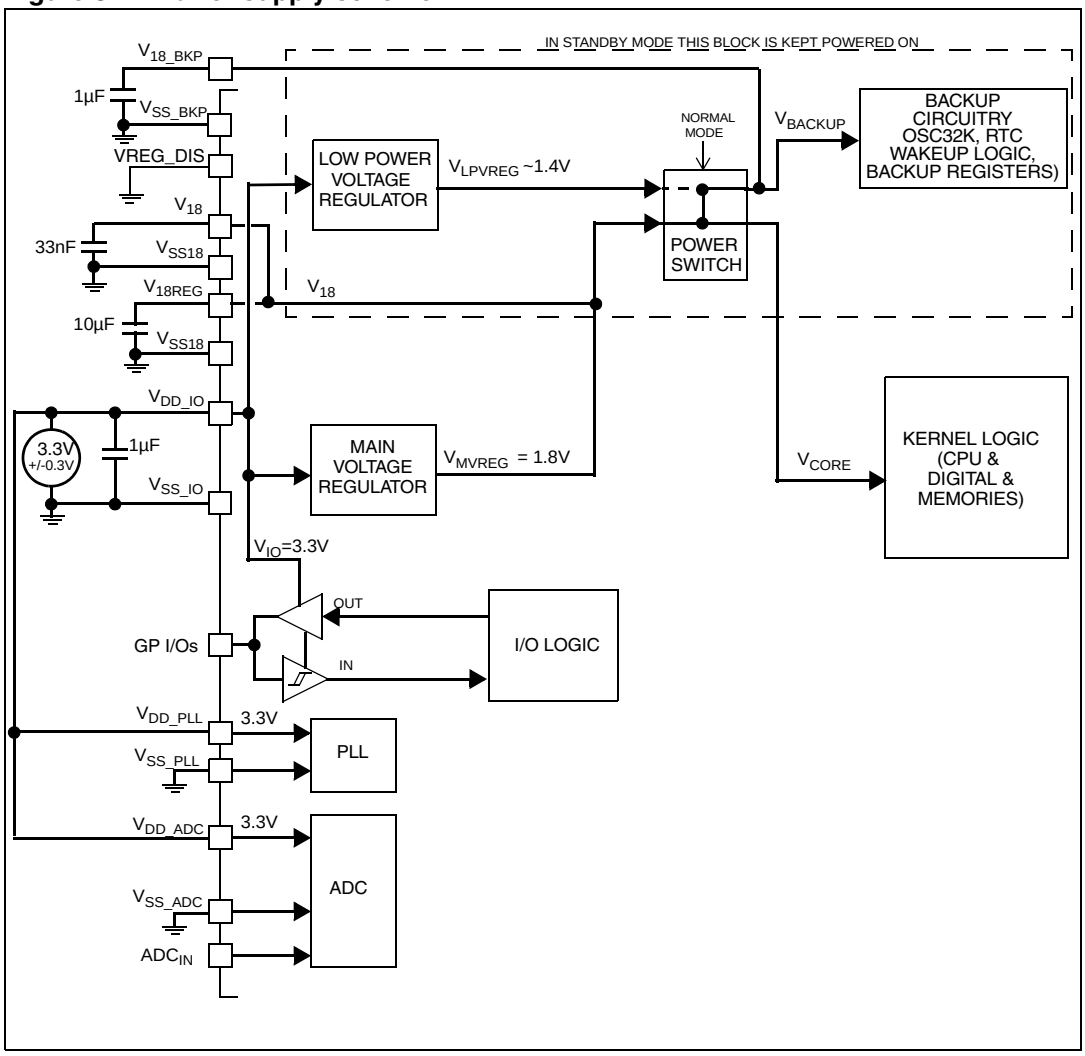
Unless otherwise specified, all typical curves are given only as design guidelines and are not tested.

6.1.6 Power supply schemes

When mentioned, some electrical parameters can refer to a dedicated power scheme among the four possibilities. The four different power schemes are described below.

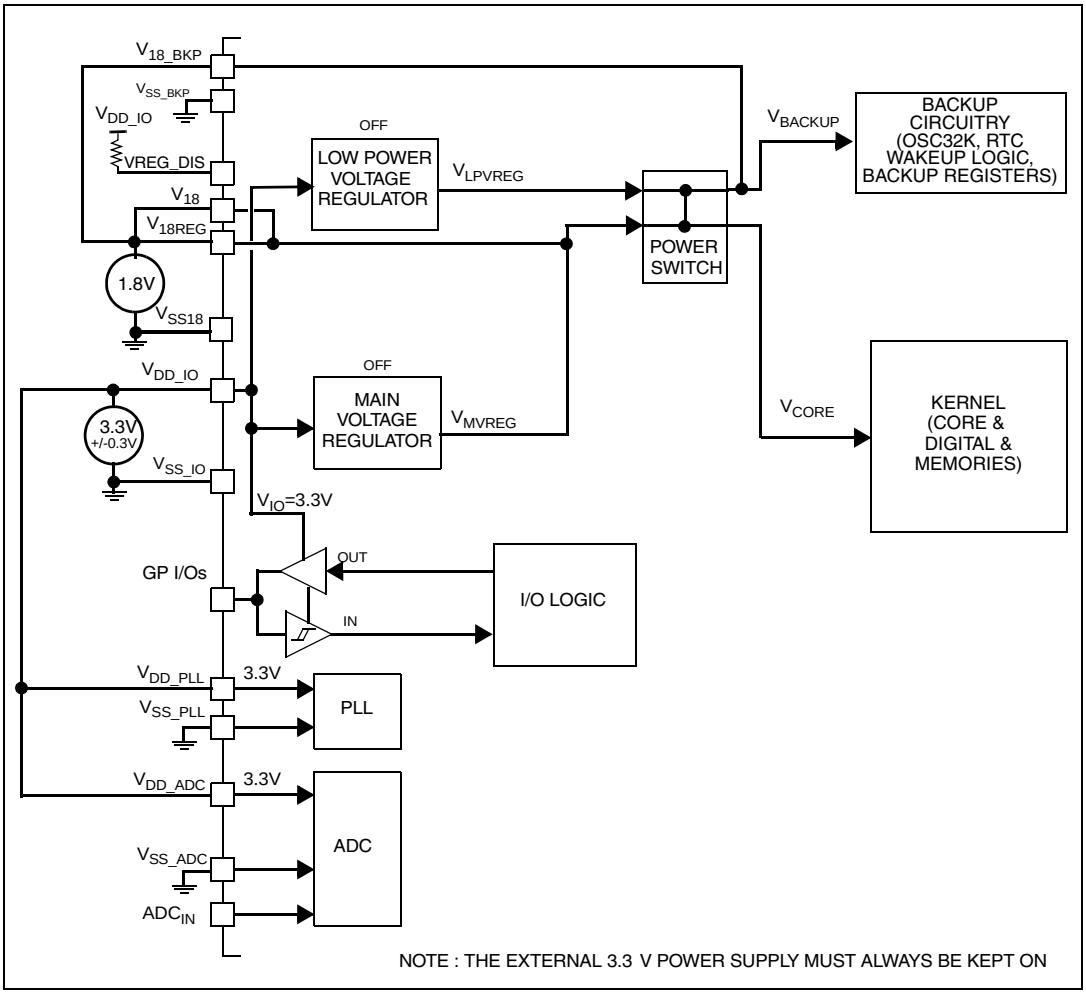
Power supply scheme 1: Single external 3.3 V power source

Figure 8. Power supply scheme 1



Power supply scheme 2: Dual external 1.8V and 3.3V supply

Figure 9. Power supply scheme 2



6.3.2 Operating conditions at power-up / power-down

Subject to general operating conditions for T_A.

Table 11. Operating conditions at power-up / power-down

Symbol	Parameter	Conditions	Min(1)	Typ	Max(1)	Unit
t_{VDD_IO}	V_{DD_IO} rise time rate		20			µs/V
					20	ms/V
t_{V18}	V_{18} rise time rate (1)	When 1.8 V power is supplied externally	20			µs/V
					20	ms/V

1. Data guaranteed by characterization, not tested in production.

6.3.3 Embedded voltage regulators

Subject to general operating conditions for V_{DD_IO}, and T_A

Table 12. Embedded voltage regulators

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{MVREG}	MVREG power supply(1)	load <150 mA	1.65	1.80	1.95	V
V_{LPVREG}	LPVREG power supply(2)	load <10 mA	1.30	1.40	1.50	V
t_{VREG_PWRUP}(1)	Voltage Regulators start-up time (to reach 90% of final V_{18} value) at V_{DD_IO} power-up(3)	V_{DD_IO} rise slope = 20 µs/V		80		µs
		V_{DD_IO} rise slope = 20 ms/V		35		ms

1. V_{MVREG} is observed on the V_{18}, V_{18REG} and V_{18BKP} pins except in the following case:
   - In STOP mode with MVREG OFF (LP_PARAM13 bit). See note 2.
   - In STANDBY mo*de. See note 2.*
2. In STANDBY mode, V_{LPVREG} is observed on the V_{18BKP} pin
   In STOP mode, V_{LPVREG} is observed on the V_{18}, V_{18REG} and V_{18BKP} pins.
3. Once V_{DD_IO} has reached 3.0 V, the RSM (Regulator Startup Monitor) generates an internal RESET during this start-up time.

Figure 16. Power consumption in STOP mode in Single supply scheme (3.3 V range)

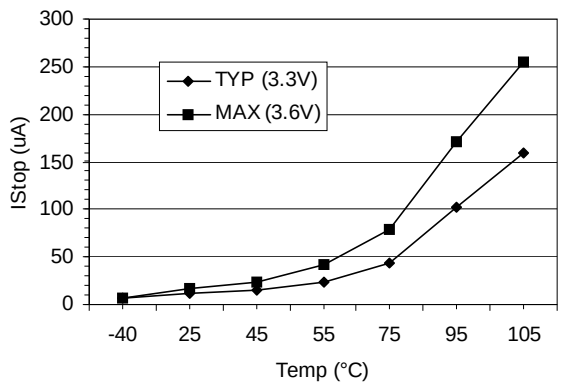


Figure 17. Power consumption in STOP mode Single supply scheme (5 V range)

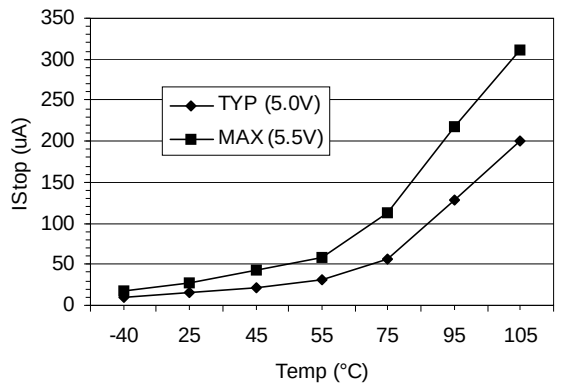


Figure 18. Power consumption in STANDBY mode (3.3 V range)

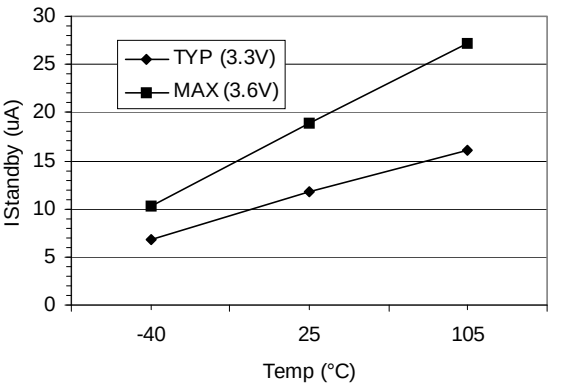
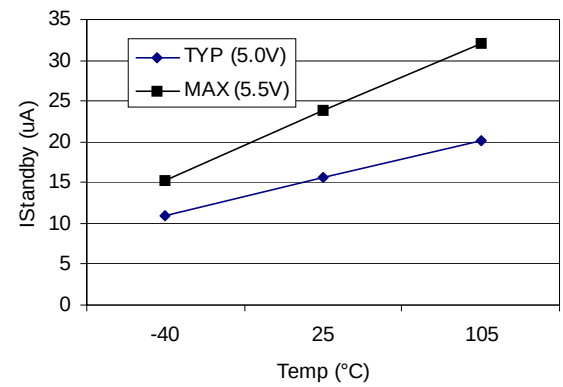


Figure 19. Power consumption in STANDBY mode (5 V range)



XRTC1 external clock source

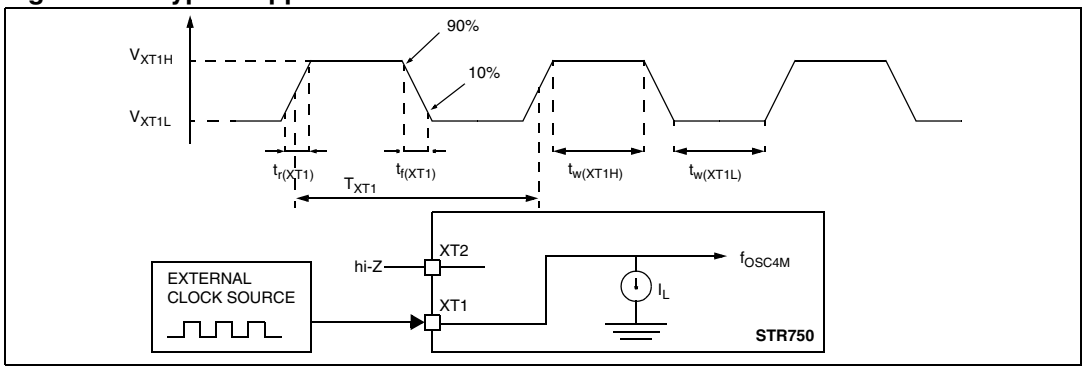
Subject to general operating conditions for V_{DD_IO}, and T_A.

Table 21. XRTC1 external clock source

Symbol	Parameter	Conditions(1)	Min	Typ	Max	Unit
f_{XRTC1}	External clock source frequency	see *Figure 20*		32.768	500	kHz
V_{XRTC1H}	XRTC1 input pin high level voltage		$0.7xV_{DD\_IO}$		V_{DD_IO}	V
V_{XRTC1L}	XRTC1 input pin low level voltage		V_{SS}		$0.3xV_{DD\_IO}$	
$t_{w(XRTC1H)}$ $t_{w(XRTC1L)}$	XRTC1 high or low time(2)		900			ns
$t_{r(XRTC1)}$ $t_{f(XRTC1)}$	XRTC1 rise or fall time(2)				50	
I_L	XRTCx Input leakage current	$V_{SS} \le V_{IN} \le V_{DD\_IO}$			±1	µA
$C_{IN(RTC1)}$	XRTC1 input capacitance(2)			5		pF
$DuCy_{(RTC1)}$	Duty cycle		30		70	%

1. Data based on typical application software.
2. Data based on design simulation and/or technology characteristics, not tested in production.

Figure 20. Typical application with an external clock source



4/8 MHz crystal / ceramic resonator oscillator (XT1/XT2)

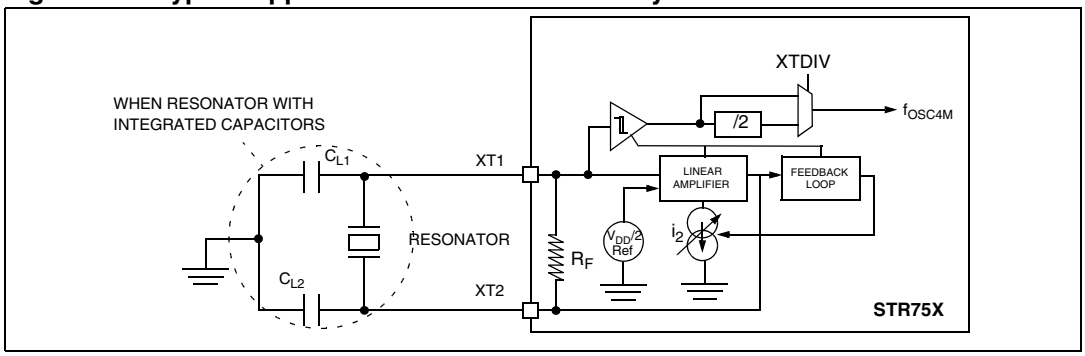
The STR750 system clock or the input of the PLL can be supplied by a OSC4M which is a 4 MHz clock generated from a 4 MHz or 8 MHz crystal or ceramic resonator. If using an 8 MHz oscillator, software set the XTDIV bit to enable a divider by 2 and generate a 4 MHz OSC4M clock. All the information given in this paragraph are based on product characterisation with specified typical external components. In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and start-up stabilization time. Refer to the crystal/ceramic resonator manufacturer for more details (frequency, package, accuracy...).

Table 22. 4/8 MHz crystal / ceramic resonator oscillator (XT1/XT2)(1)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f_{OSC4M}	Oscillator frequency	4 MHz Crystal/Resonator Oscillator connected on XT1/XT2 XTDIV=0 or 8 MHz Crystal/Resonator Oscillator connected on XT1/XT2 XTDIV=1		4		MHz
R_F	Feedback resistor		200	240	270	kΩ
C_{L1}(2) C_{L2}	Recommended load capacitance versus equivalent serial resistance of the crystal or ceramic resonator (R_S)(3)	R_S=200Ω			60	pF
i_2	XT2 driving current	V_{DD_IO}=3.3 V or 5.0 V		425		µA
$t_{SU(OSC4M)}$(4)	Startup time at V_{DD_IO} power-up			1		ms

1. Resonator characteristics given by the crystal/ceramic resonator manufacturer.
2. For C_{L1} and C_{L2} it is recommended to use high-quality ceramic capacitors in the 5-pF to 25-pF range (typ.) designed for high-frequency applications and selected to match the requirements of the crystal or resonator. C_{L1} and C_{L2}, are usually the same size. The crystal manufacturer typically specifies a load capacitance which is the series combination of C_{L1} and C_{L2}. PCB and MCU pin capacitance must be included when sizing C_{L1} and C_{L2} (10 pF can be used as a rough estimate of the combined pin and board capacitance).
3. The relatively low value of the RF resistor offers a good protection against issues resulting from use in a humid environment, due to the induced leakage and the bias condition change. However, it is recommended to take this point into account if the MCU is used in tough humidity conditions.
4. $t_{SU(OSC4M)}$ is the typical start-up time measured from the moment V_{DD_IO} is powered (with a quick V_{DD_IO} ramp-up from 0 to 3.3V (<50µs) to a stabilized 4MHz oscillation is reached. This value is measured for a standard crystal resonator and it can vary significantly with the crystal/ceramic resonator manufacturer.

Figure 21. Typical application with a 4 or 8 MHz crystal or ceramic resonator



PLL characteristics

Subject to general operating conditions for V_{DD_IO}, and T_A.

Table 24. PLL characteristics

Symbol	Parameter	Test Conditions	Value			Unit
			Min	Typ	Max(1)	
f_{PLL_IN}	PLL input clock			4.0		MHz
	PLL input clock duty cycle		40		60	%
f_{PLL_OUT}	PLL multiplier output clock	f_{PLL_IN}x 24			165	MHz
f_{VCO}	VCO frequency range	When PLL operates (locked)	336		960	MHz
t_{LOCK}	PLL lock time				300	µs
$\Delta t_{JITTER1}$(2)(3)	Single period jitter (+/-3Σ peak to peak)	f_{PLL_IN} = 4 MHz(4) V_{DD_IO} is stable			+/-250	ps
$\Delta t_{JITTER2}$(2)(3)	Long term jitter (+/-3Σ peak to peak)	f_{PLL_IN} = 4 MHz(4) V_{DD_IO} is stable			+/-2.5	ns
$\Delta t_{JITTER3}$(2)(3)	Cycle to cycle jitter (+/-3Σ peak to peak)	f_{PLL_IN} = 4 MHz(4) V_{DD_IO} is stable			+/-500	ps

1. Data based on product characterisation, not tested in production.
2. Refer to jitter terminology in *: PLL characteristics on page 47* for details on how jitter is specified.
3. The jitter specification holds true only up to 50mV (peak-to-peak) noise on V_{DDA_PLL} and V_{18} supplies. Jitter will increase if the noise is more than 50mV. In addition, it assumes that the input clock has no jitter.
4. The PLL parameters (MX1, MX0, PRESC1, PRESC2) must respect the constraints described in*: PLL characteristics on page 47*.

Internal RC oscillators (FREEOSC & LPOSC)

Subject to general operating conditions for V_{DD_IO}, and T_A.

Table 25. Internal RC oscillators (FREEOSC & LPOSC)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$f_{CK\_FREEOSC}$	FREEOSC Oscillator Frequency		3	5	8	MHz
f_{CK_LPOSC}	LPOSC Oscillator Frequency		150	300	500	kHz

Table 37. PWM Timer (PWM)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_{res(PWM)}$	PWM resolution time	$f_{CK\_TIM(MAX)} = f_{CK\_SYS}$	1			t_{CK_TIM}
		$f_{CK\_TIM} = f_{CK\_SYS}$ = 60 MHz	16.6(1)			ns
Res_{PWM}	PWM resolution				16	bit
V_{OS}(1)	PWM/DAC output step voltage	V_{DD_IO}=3.3 V, Res=16-bits		50(1)		µV
		V_{DD_IO}=5.0 V, Res=16-bits		76(1)		µV
$t_{COUNTER}$	Timer clock period when internal clock is selected		1		65536	t_{CK_TIM}
		f_{CK_TIM}=60 MHz	0.0166		1087	µs
t_{MAX_COUNT}	Maximum Possible Count				65536x 65536	t_{CK_TIM}
		$f_{CK\_TIM} = f_{CK\_SYS}$ = 60 MHz			71.58	s

1. Take into account the frequency limitation due to the I/O speed capability when outputting the PWM to an I/O pin, as described in *: Output speed on page 57*.

Figure 31. TI configuration - master mode, single transfer

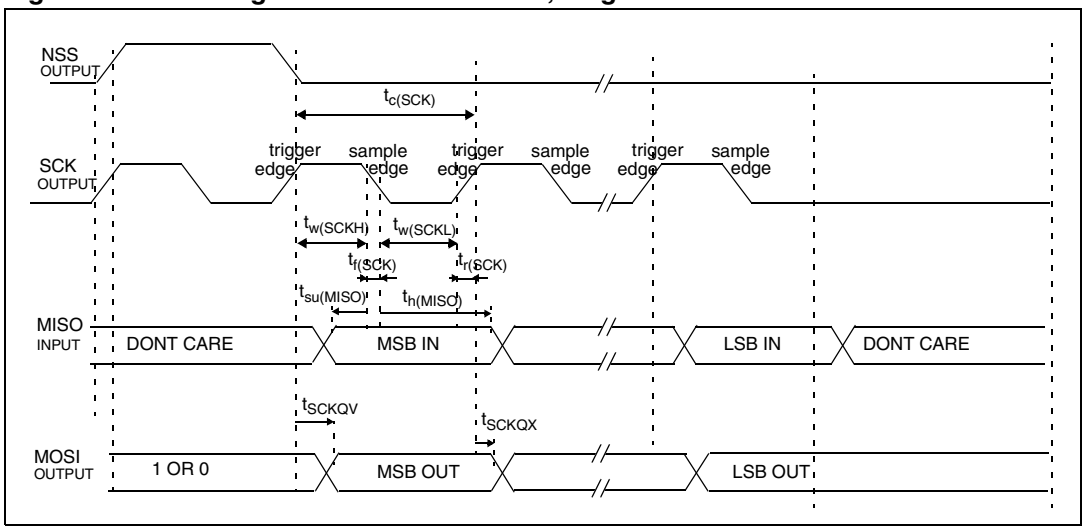


Figure 32. TI configuration - master mode, continuous transfer

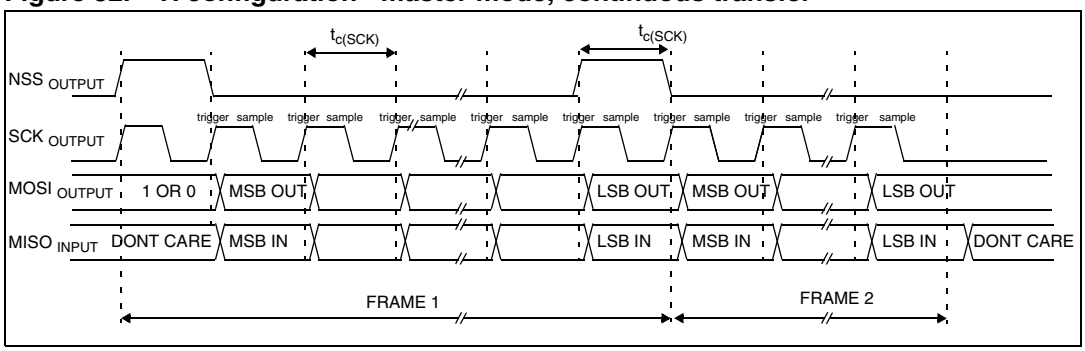


Table 44. USB: Full speed electrical characteristics

Symbol	Parameter	Conditions	Min	Max	Unit
t_{rfm}	Rise/ Fall Time matching	t_r/t_f	90	110	%
V_{CRS}	Output signal Crossover Voltage		1.3	2.0	V

1. Measured from 10% to 90% of the data signal. For more detailed informations, please refer to USB Specification - Chapter 7 (version 2.0).

General PCB design guidelines

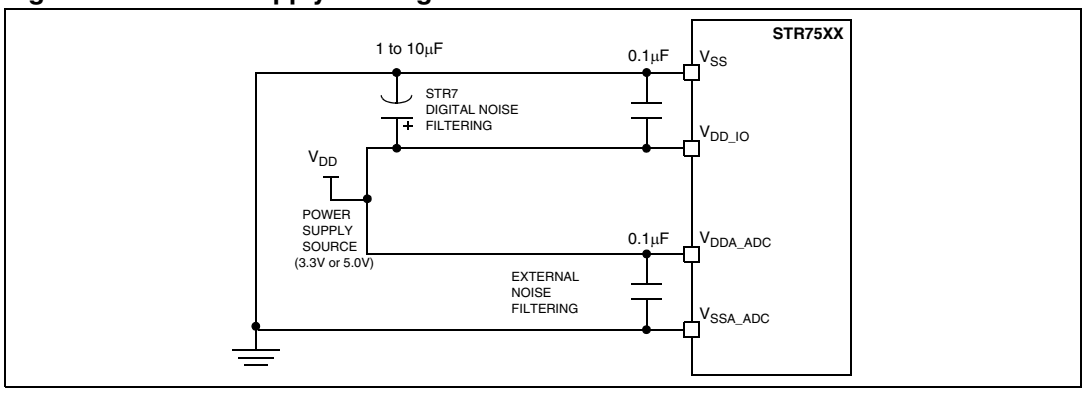
To obtain best results, some general design and layout rules should be followed when designing the application PCB to shield the noise-sensitive, analog physical interface from noise-generating CMOS logic signals.

- Use separate digital and analog planes. The analog ground plane should be connected to the digital ground plane via a single point on the PCB.
- Filter power to the analog power planes. It is recommended to connect capacitors, with good high frequency characteristics, between the power and ground lines, placing 0.1 µF and optionally, if needed 10 pF capacitors as close as possible to the STR7 power supply pins and a 1 to 10 µF capacitor close to the power source (see *Figure 43*).
- The analog and digital power supplies should be connected in a star network. Do not use a resistor, as V_{DDA_ADC} is used as a reference voltage by the A/D converter and any resistance would cause a voltage drop and a loss of accuracy.
- Properly place components and route the signal traces on the PCB to shield the analog inputs. Analog signals paths should run over the analog ground plane and be as short as possible. Isolate analog signals from digital signals that may switch while the analog inputs are being sampled by the A/D converter. Do not toggle digital outputs near the A/D input being converted.

Software filtering of spurious conversion results

For EMC performance reasons, it is recommended to filter A/D conversion outliers using software filtering techniques.

Figure 43. Power supply filtering

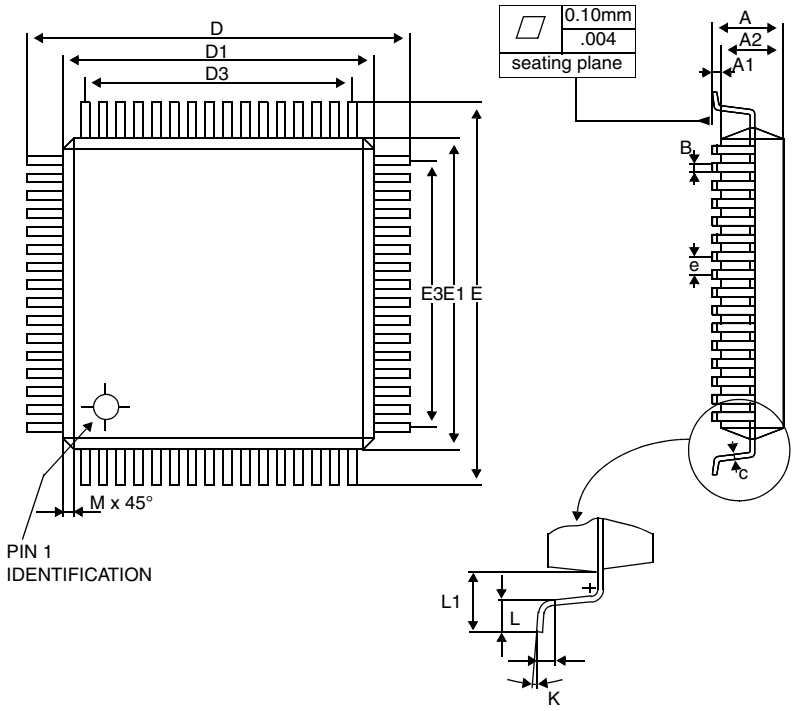


7 Package characteristics

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK® is an ST trademark.

7.1 Package mechanical data

Figure 45. 64-pin low profile quad flat package (10x10)



Dim.	mm			inches[1]		
	Min	Typ	Max	Min	Typ	Max
A			1.60			0.0630
A1	0.05		0.15	0.0020		0.0059
A2	1.35	1.40	1.45	0.0531	0.0551	0.0571
b	0.17	0.22	0.27	0.0067	0.0087	0.0106
C	0.09		0.20	0.0035		0.0079
D		12.00			0.4724	
D1		10.00			0.3937	
E		12.00			0.4724	
E1		10.00			0.3937	
e		0.50			0.0197	
K	0°	3.5°	7°	0°	3.5°	7°
L	0.45	0.60	0.75	0.0177	0.0236	0.0295
L1		1.00			0.0394	
	Number of pins					
N	64					

1. Values in inches are converted from mm and rounded to 4 decimal digits.

7.2 Thermal characteristics

The maximum chip junction temperature (T_{Jmax}) must never exceed the values given in *Table 10: General operating conditions on page 34*.

The maximum chip-junction temperature, T_{Jmax}, in degrees Celsius, may be calculated using the following equation:

$$T_{Jmax} = T_{Amax} + (P_{Dmax} \times \Theta_{JA})$$

Where:

- T_{Amax} is the maximum Ambient Temperature in °C,
- Θ_{JA} is the Package Junction-to-Ambient Thermal Resistance, in ° C/W,
- P_{Dmax} is the sum of P_{INTmax} and $P_{I/Omax}$ ($P_{Dmax} = P_{INTmax} + P_{I/Omax}$),
- P_{INTmax} is the product of I_{DD} and V_{DD}, expressed in Watts. This is the maximum chip internal power.
- $P_{I/Omax}$ represents the maximum Power Dissipation on Output Pins.
  Where:
  $P_{I/Omax} = \Sigma (V_{OL}*I_{OL}) + \Sigma((V_{DD}-V_{OH})*I_{OH})$,
  taking into account the actual V_{OL} / I_{OL} and V_{OH} / I_{OH} of the I/Os at low and high level in the application.

Table 48. Thermal characteristics(1)

Symbol	Parameter	Value	Unit
Θ_{JA}	**Thermal Resistance Junction-Ambient** LQFP 100 - 14 x 14 mm / 0.5 mm pitch	46	°C/W
Θ_{JA}	**Thermal Resistance Junction-Ambient** LQFP 64 - 10 x 10 mm / 0.5 mm pitch	45	°C/W
Θ_{JA}	**Thermal Resistance Junction-Ambient** LFBGA 64 - 8 x 8 x 1.7mm	58	°C/W
Θ_{JA}	**Thermal Resistance Junction-Ambient** LFBGA 100 - 10 x 10 x 1.7mm	41	°C/W

1. Thermal resistances are based on JEDEC JESD51-2 with 4-layer PCB in a natural convection environment.

7.2.1 Reference document

JESD51-2 Integrated Circuits Thermal Test Method Environment Conditions - Natural Convection (Still Air). Available from www.jedec.org

7.2.2 Selecting the product temperature range

When ordering the microcontroller, the temperature range is specified in the order code *Table 49: Order codes on page 81*.

The following example shows how to calculate the temperature range needed for a given application.

Assuming the following application conditions:

Maximum ambient temperature T_{Amax}= 82 °C (measured according to JESD51-2), I_{DDmax}=8 mA, V_{DD} = 5 V, maximum 20 I/Os used at the same time in output at low level with I_{OL} = 8 mA, V_{OL}= 0.4 V

$$P_{INTmax} = 8 \text{ mA} \times 5 \text{ V} = 400 \text{ mW}$$

$$P_{IOmax} = 20 \times 8 \text{ mA} \times 0.4\text{V} = 64 \text{ mW}$$

This gives: P_{INTmax}= 400 mW and P_{IOmax} 64 mW:

$$P_{Dmax} = 400 \text{ mW} + 64 \text{ mW}$$

Thus: P_{Dmax} = 464 mW

Using the values obtained in *Table 48* T_{Jmax} is calculated as follows:

– For LQFP100, 46°C/W

T_{Jmax} = 82° C + (46° C/W x 464 mW) = 82°C + 21°C = 103° C

This is within the range of the suffix 6 version parts (-40 < T_J < 105° C).

In this case, parts must be ordered at least with the temperature range suffix 6 (see *Table 49: Order codes on page 81*).

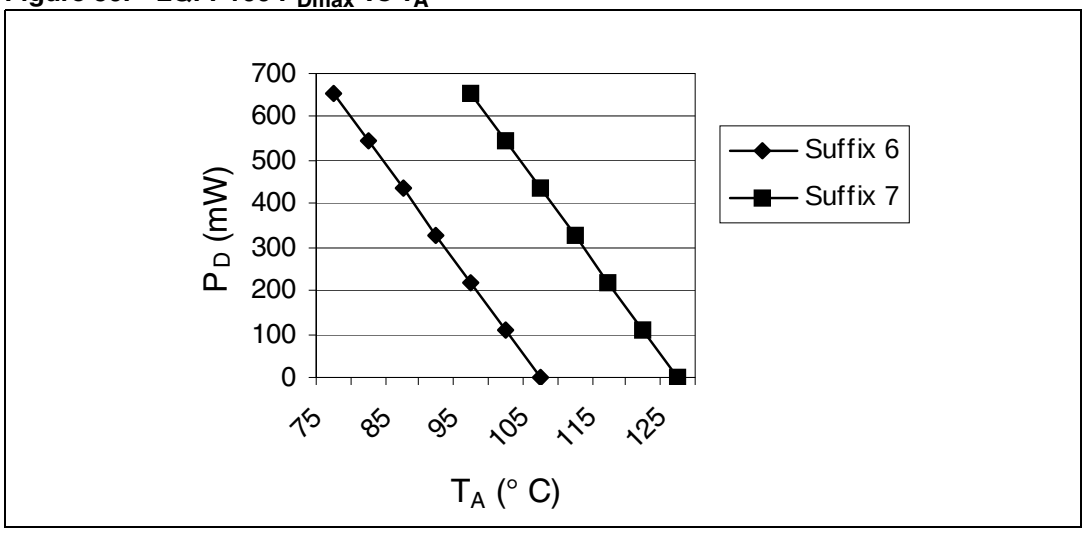
– For BGA64, 58°C/W

T_{Jmax} = 82° C + (58° C/W x 464 mW) = 82°C + 27°C = 109° C

This is within the range of the suffix 7 version parts (-40 < T_J < 125° C).

In this case, parts must be ordered at least with the temperature range suffix 7 (see *Table 49: Order codes on page 81*).

Figure 50. LQFP100 P_{Dmax} vs T_A



8 Order codes

Table 49. Order codes

Order code	Flash Prog. Memory (Bank 0) Kbytes	Package	CAN Periph	USB Periph	Nominal Temp. Range (T_A)
STR750FV0T6	64	LQFP100 14x14	Yes	Yes	-40 to +85°C
STR750FV1T6	128				
STR750FV2T6	256				
STR750FV0H6	64	LFBGA100 10x10			
STR750FV1H6	128				
STR750FV2H6	256				
STR751FR0T6	64	LQFP64 10x10	-	Yes	-40 to +85°C
STR751FR1T6	128				
STR751FR2T6	256				
STR751FR0H6	64	LFBGA64 8x8			
STR751FR1H6	128				
STR751FR2H6	256				
STR752FR0T6	64	LQFP64 10x10	Yes	-	-40 to +85°C
STR752FR1T6	128				
STR752FR2T6	256				
STR752FR0H6	64	LFBGA64 8x8			
STR752FR1H6	128				
STR752FR2H6	256				
STR752FR0T7	64	LQFP64 10x10	Yes	-	-40 to +105°C
STR752FR1T7	128				
STR752FR2T7	256				
STR752FR0H7	64	LFBGA64 8x8			
STR752FR1H7	128				
STR752FR2H7	256				
STR755FR0T6	64	LQFP64 10x10	-	-	-40 to +85°C
STR755FR1T6	128				
STR755FR2T6	256				
STR755FR0H6	64	LFBGA64 8x8			
STR755FR1H6	128				
STR755FR2H6	256				